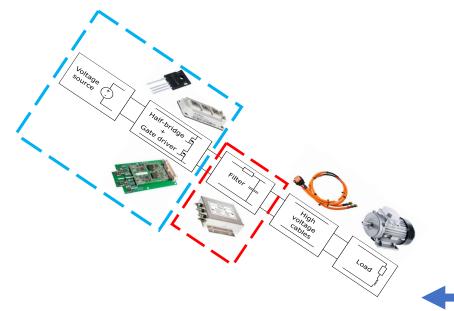


Double pulse testing

Philip Abrahamsson



IMZ120R140M1H CoolSIC" 1200V SIC Trench MOSFET							
CoolSiC™ 1200V SiC Tren Electrical Characteristics	ch MOSFE	r					
3.3 Switching	characte	eristics					
Table 6 Switching cl	naracteristi	cs, Inductive load 4					
Parameter	Symbol	Conditions	Value			Unit	
			min.	typ.	max.		
MOSFET Characteristics, 7	vj = 25°C						
Turn-on delay time	taioni	V ₀₀ = 800V, I ₀ = 6A,		5			
Rise time	t,	$V_{GS} = 0/18V, R_{G,ext} = 2\Omega,$	-	2	-		
Turn-off delay time	f _{d(off)}	$L_{\sigma} = 40 \text{nH},$	-	10.3		ns	
Fall time	ti	diode:	-	11.6	-		
Turn-on energy	Ece	body diode at V _{GS} = 0V	-	62	-		
Turn-off energy	Ect	see Fig. E		12		μJ	
Total switching energy	Etot		-	74	-		
Body Diode Characteristic	s, T _{vi} = 25°C						
Diode reverse recovery	Qrr	$V_{00} = 800V, I_{SD} = 6A,$					
charge		V _{GS} at diode = 0V,	-	100	-	nC	
Diode peak reverse	Inn	dii/dt=1000A/µs,				-	
recovery current		Q _{rr} includes also Q _C , see Fig. C - 2 - A	Α				
				2			



Other applications

Power Transistor

- It takes some time for the current and voltage to fall/rise
- Losses are generated during a switching event



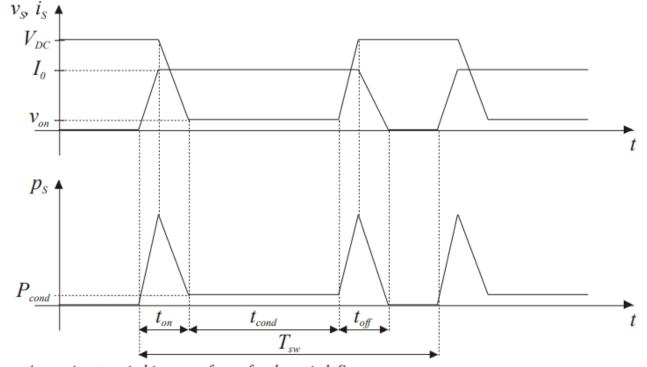
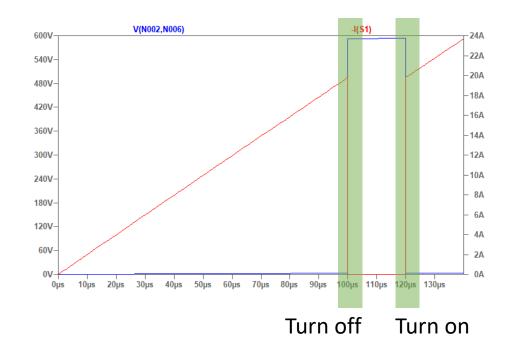


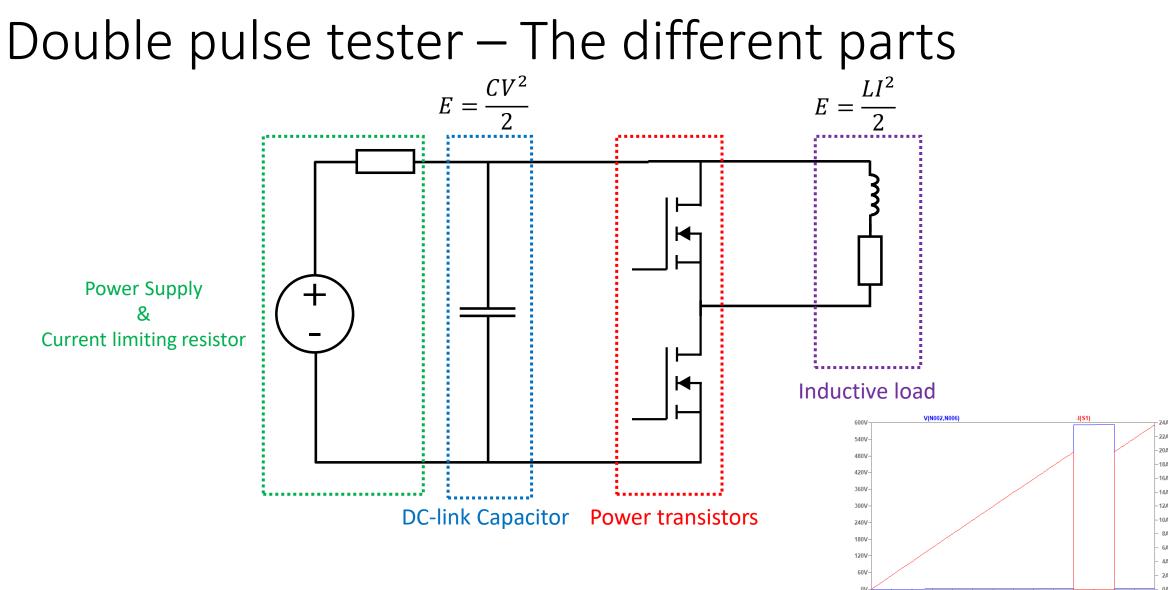
Figure 6.2: Approximate switching waveforms for the switch S.

Measure switching characteristics

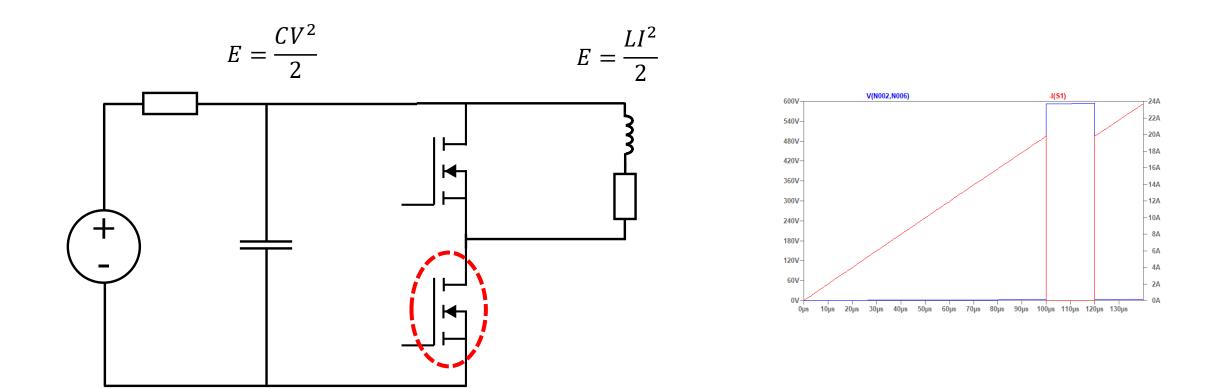
- Measure current and voltage during turn on and off events.
- Double pulse testing

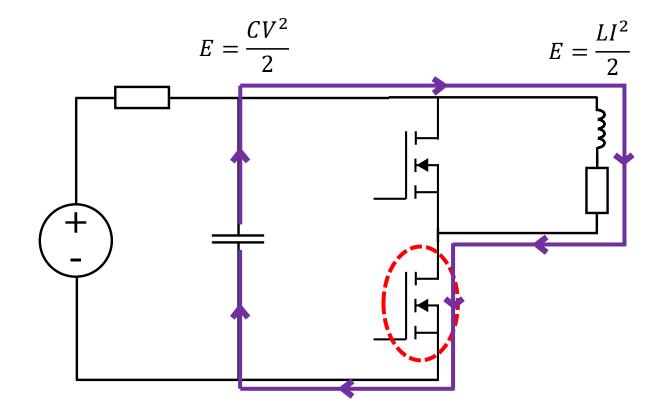
IMZ120R1 CoolSiC™ 1	infineon						
Electrical Ch	naracteristics						
3.3	Switchin	g charact	eristics				
Table 6	Switching c	haracteristi	cs, Inductive load ⁴				
Parameter		Symbol	Conditions	Value			Unit
				min.	typ.	max.	
MOSFET Ch	aracteristics,	T _{vj} = 25°C			·		
Turn-on del	ay time	$t_{d(on)}$	$V_{DD} = 800V, I_D = 6A,$ $V_{GS} = 0/18V, R_{G,ext} = 2\Omega,$	-	5	-	
Rise time		tr		-	2	-	
Turn-off del	ay time	$t_{d(off)}$	$L_{\sigma} = 40$ nH,	-	10.3	-	ns
Fall time		t _f	diode:	-	11.6	-	
Turn-on ene	ergy	Eon	body diode at $V_{GS} = 0V$	-	62	-	
Turn-off ene	ergy	$E_{\rm off}$	see Fig. E	-	12	-	μJ
Total switch	ning energy	E _{tot}		-	74	-	
Body Diode	Characteristi	cs, $T_{vj} = 25^{\circ}C$				L	
Diode revers charge	se recovery	Qrr	$V_{DD} = 800V, I_{SD} = 6A,$ V_{GS} at diode = 0V,	-	100	-	nC
Diode peak recovery cu		Irrm	di _f /dt= 1000A/μs, Q _{rr} includes also Q _c , see Fig. C	-	2	-	A

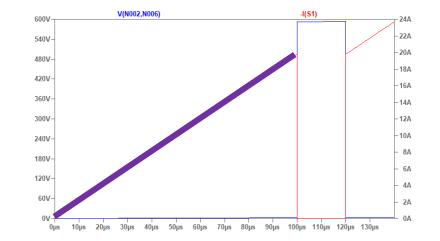


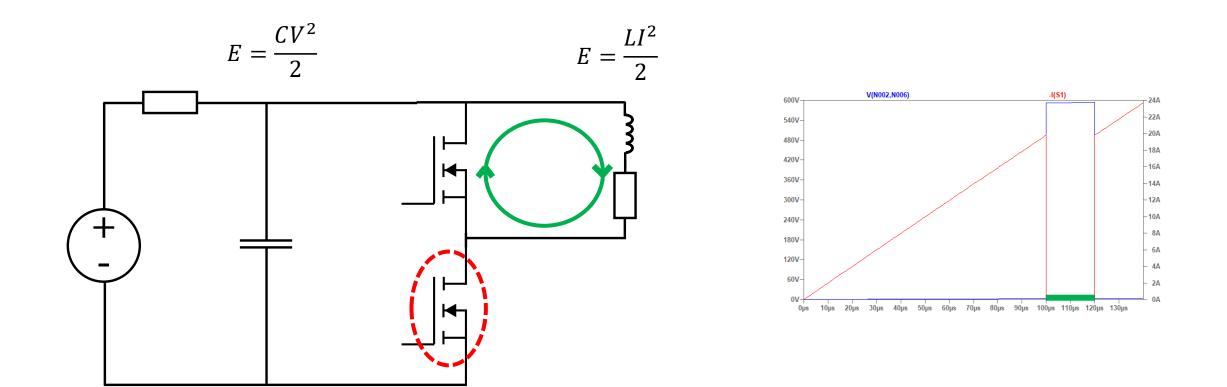


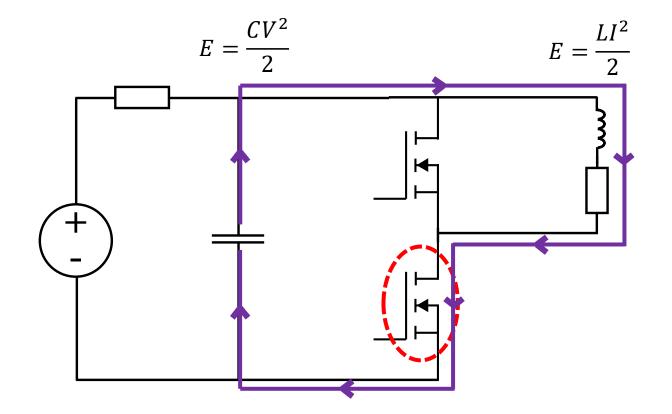
⁰µs 10µs 20µs 30µs 40µs 50µs 60µs 70µs 80µs 90µs 100µs 110µs 120µs 130µs

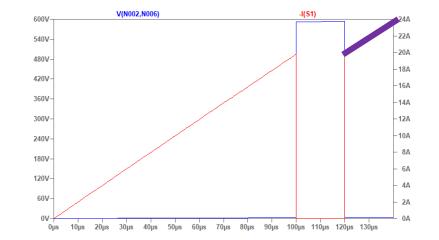


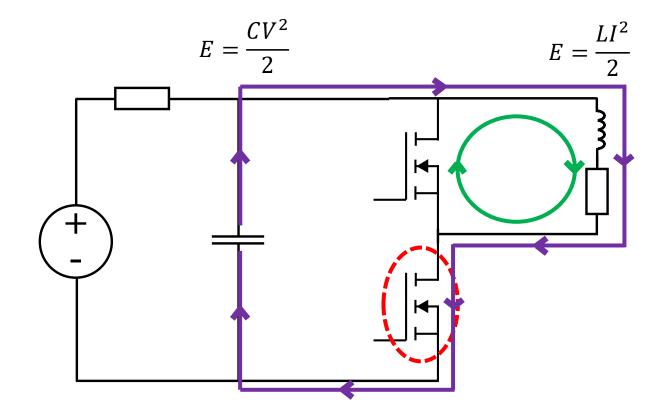


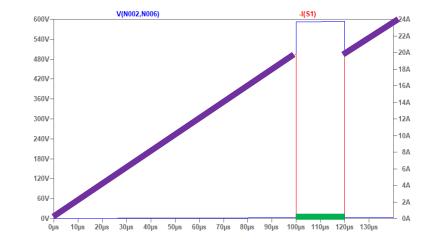






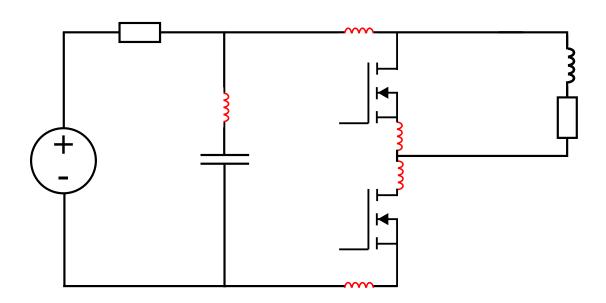


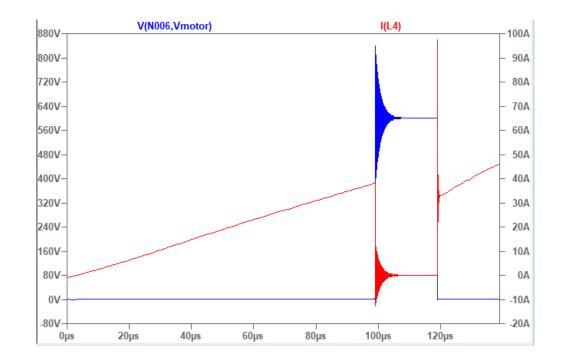




Double pulse tester – Parasitics

- Paracitics are present in any real circuit
- Non ideal switching events





PCB design

• A good PCB design can reduce stray inductance

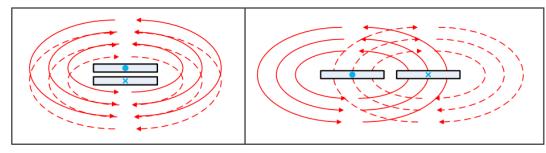


Figure 6: Parallel plate overlap

Figure 7: Coplanar plate overlap

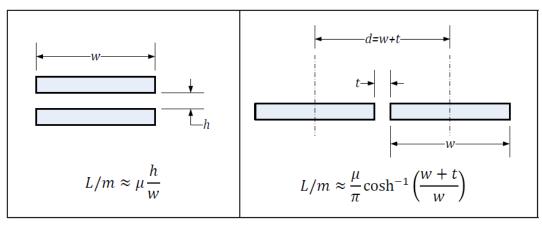
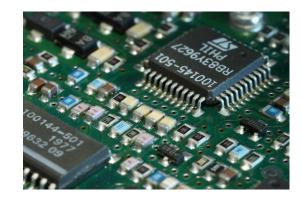
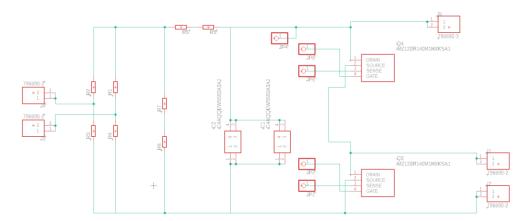
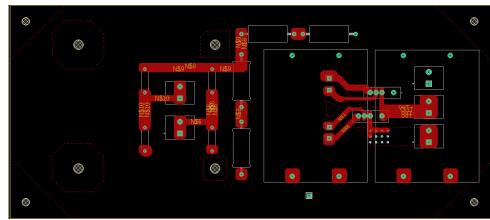


Figure 8: Parallel plate inductance approximation

Figure 9: Coplanar plate inductance approximation







Results - PCB



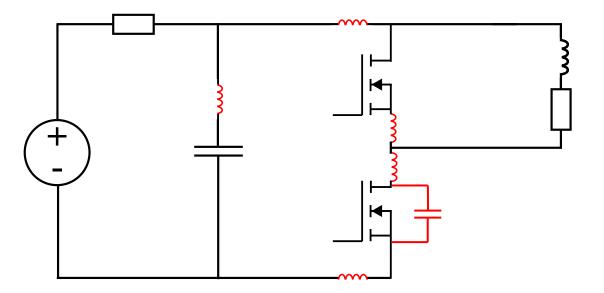


Results

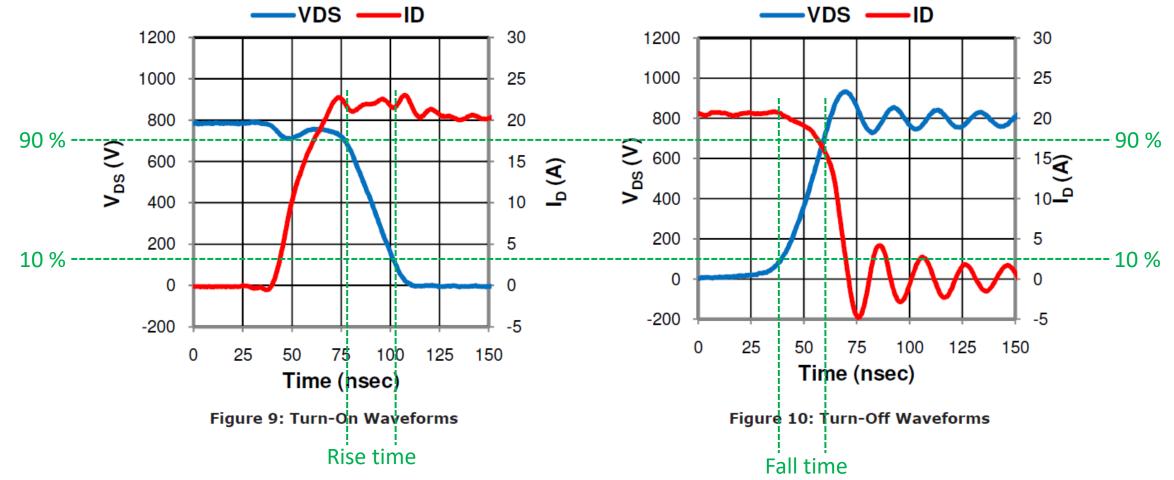
• Video from the lab

Results

• Ringing is also caused by capacitance in the circuit

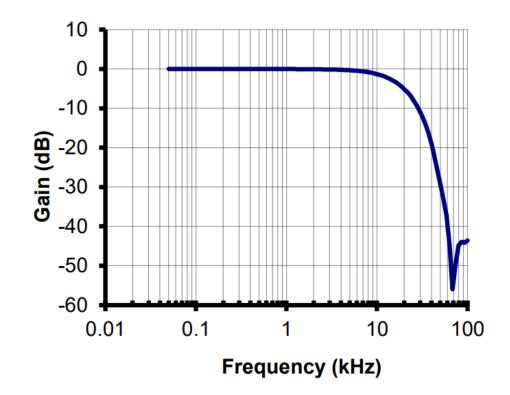


Results - Measurements



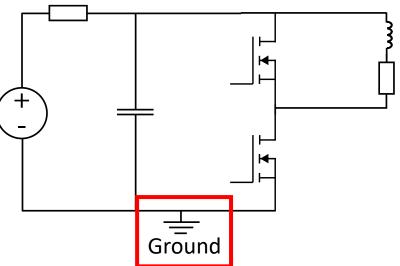
Measurement equipment - Properties

- Bandwidth
- Delay
- Accuracy

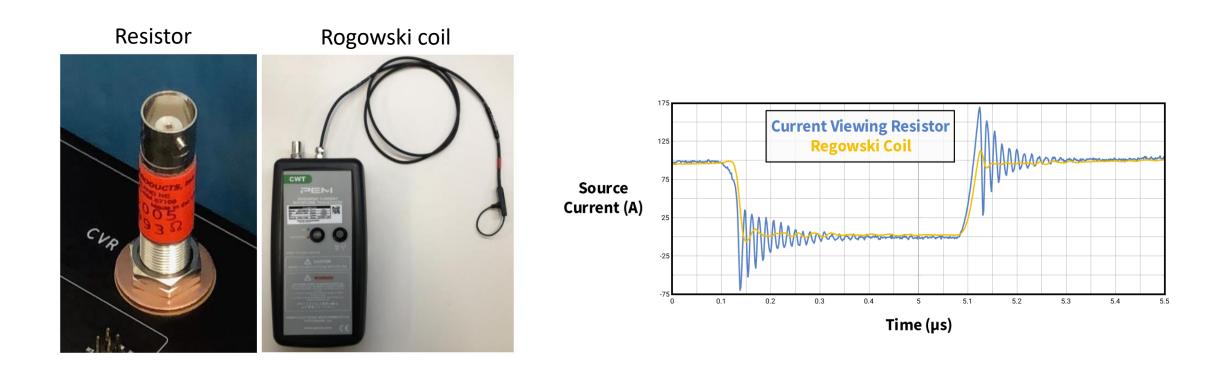


Measurement equipment – Examples of probes





Measurement equipment – Examples of probes

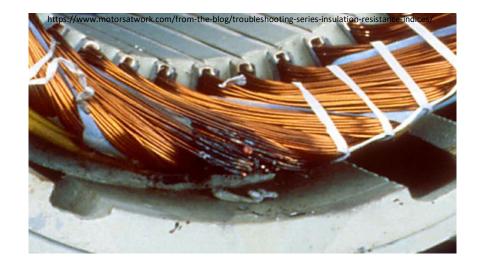


Figures: CREE, CPWR-AN45 Wolfspeed WolfPACK[™] Dynamic Performance Application Note

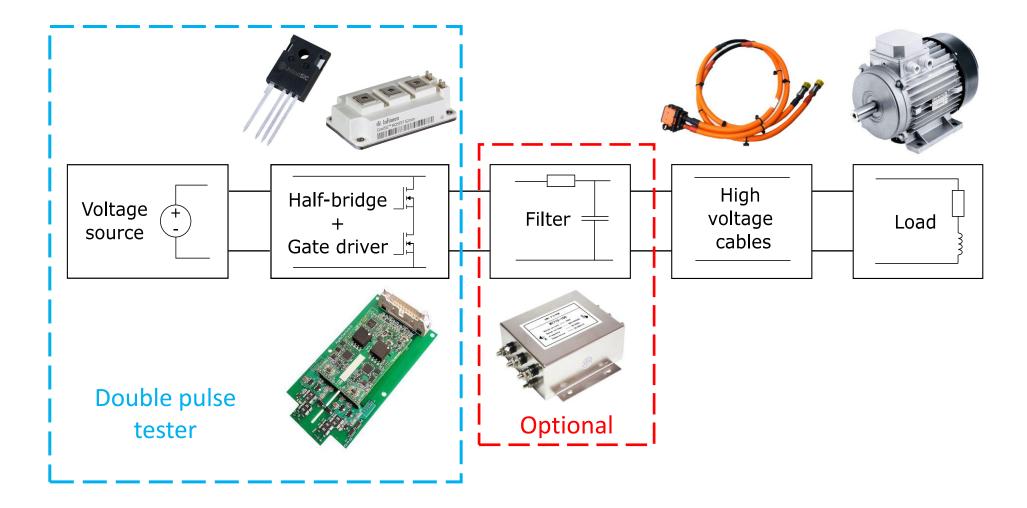
What else can the double pulse tester be used for?

Investigate how switching events effect electric insulation

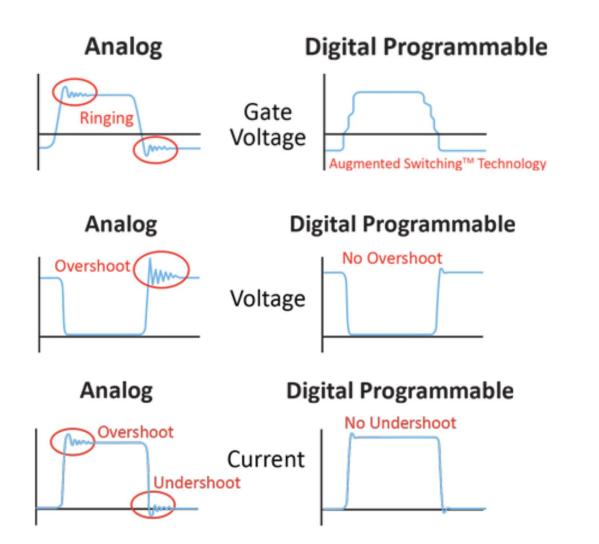
- Switching events cause high dV/dt
- High dV/dt can break down insulation in electric machines



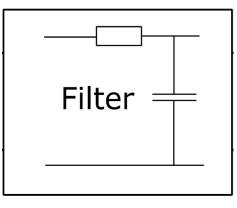
Test of electric insulation



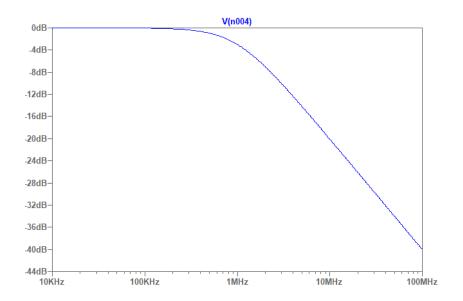
Programmable gate driver

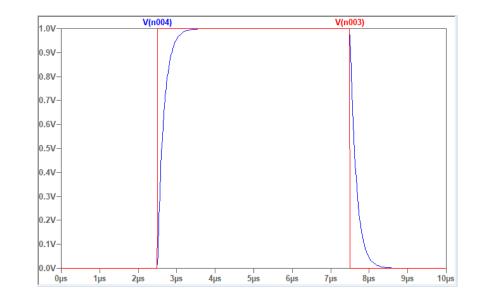






Filter - Reduce dV/dt





Summary

- A double pulse tester can be used to characterize power transistors
- PCB design is important for proper switching performance
- High bandwidth is needed for the measurement equipment

Questions?